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Kind regards,

Team Nexperia



PUMX2

NPN/NPN general-purpose double transistors

Rev. 02 — 17 November 2009

Product data sheet

1. Product profile

1.1 General description

NPN/NPN general-purpose double transistors in a small SOT363 (SC-88) Surface Mounted Device (SMD) plastic package.

1.2 Features

- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs

1.3 Applications

■ General-purpose switching and amplification

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transistor						
V_{CEO}	collector-emitter voltage	open base	-	-	50	٧
I _C	collector current		-	-	150	mA
h _{FE}	DC current gain	$V_{CE} = 6 \text{ V}; I_{C} = 1 \text{ mA}$	120	250	560	

2. Pinning information

Table 2. Pinning

	9		
Pin	Description	Simplified outline	Symbol
1	emitter TR1		
2	emitter TR2	6 5 4	6 5 4
3	base TR2		TR1 TR2
4	collector TR2	0	
5	base TR1	□1 □2 □3	1 2 3
6	collector TR1		006aaa653



3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PUMX2	SC-88	plastic surface mounted package; 6 leads	SOT363

4. Marking

Table 4. Marking codes

Type number	Marking code ^[1]
PUMX2	Z1*

^{[1] * = -:} made in Hong Kong

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per transist	or				
V_{CBO}	collector-base voltage	open emitter	-	60	V
V_{CEO}	collector-emitter voltage	open base	-	50	V
V _{EBO}	emitter-base voltage	open collector	-	7	V
I _C	collector current		-	150	mA
I _{CM}	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	200	mA
I _{BM}	peak base current	single pulse; $t_p \le 1 \text{ ms}$	-	100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$	<u>[1]</u> -	180	mW
Per device					
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$	<u>[1]</u> -	300	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

^{* =} p: made in Hong Kong

^{* =} t: made in Malaysia

^{* =} W: made in China

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transistor						
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1] -	-	694	K/W
Per device	e					
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1] -	-	417	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

7. Characteristics

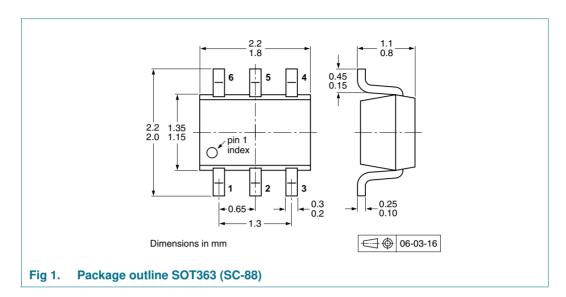
Table 7. Characteristics

T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per trans	Per transistor					
I _{CBO} collector-base cut-off current		$V_{CB} = 60 \text{ V}; I_E = 0 \text{ A}$	-	-	100	nA
	$V_{CB} = 60 \text{ V}; I_E = 0 \text{ A};$ $T_j = 150 \text{ °C}$	-	-	50	μΑ	
I _{EBO}	emitter-base cut-off current	$V_{EB} = 7 \text{ V}; I_{C} = 0 \text{ A}$	-	-	100	nA
h _{FE}	DC current gain	$V_{CE} = 6 \text{ V}; I_{C} = 1 \text{ mA}$	120	250	560	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 50 \text{ mA}; I_B = 5 \text{ mA}$	-	-	250	mV
f _T	transition frequency	$V_{CE} = 12 \text{ V}; I_E = 2 \text{ mA};$ f = 100 MHz	100	-	-	MHz
C _c	collector capacitance	$V_{CB} = 12 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz	-	-	3	pF

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Package outline 8.



Packing information 9.

Product data sheet

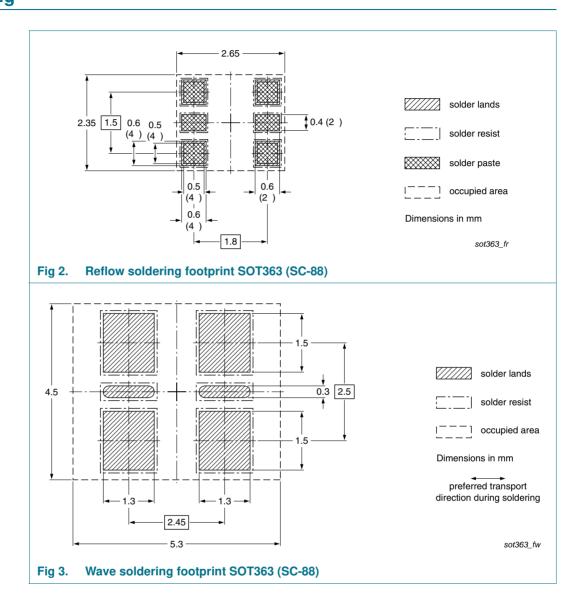
Table 8. **Packing methods**

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description P		Packing quantity	
				3000	10000
PUMX2 SOT363 4		4 mm pitch, 8 mm tape and reel; T1	[2]	-115	-135
		4 mm pitch, 8 mm tape and reel; T2	[3]	-125	-165

- [1] For further information and the availability of packing methods, see Section 13.
- T1: normal taping
- T2: reverse taping

10. Soldering





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NPN/NPN general-purpose double transistors

11. Revision history

Table 9. **Revision history**

Product data sheet

Document ID	Release date	Data sheet status	Change notice	Supersedes
PUMX2_2	20091117	Product data sheet	-	PUMX2_1
Modifications:		neet was changed to reflect w legal definitions and disc		
	 Figure 1 "Pa 	ackage outline SOT363 (SC	<u>2-88)"</u> : updated	
	 Figure 2 "Re 	eflow soldering footprint SC	T363 (SC-88)": updated	
	 Figure 3 "W 	ave soldering footprint SOT	<u>[363 (SC-88)"</u> : updated	
PUMX2_1	20051110	Product data sheet	-	-



NPN/NPN general-purpose double transistors

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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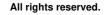
NPN/NPN general-purpose double transistors

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Document identifier: PUMX2_2

